

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	119	semiconductor with light adj intercept\$3	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM TDB	2003/01/0 4 11:08
2	BRS	L2	20	1 and liquid adj crystal	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM TDB	2003/01/0 4 10:38
3	BRS	L3	1	"5754266".PN.	USPA T	2003/01/0 4 10:44
4	BRS	L4	1	"5694188".PN.	USPA T	2003/01/0 4 10:45
5	BRS	L5	1	"5672888".PN.	USPA T	2003/01/0 4 10:45
6	BRS	L6	1	"5668650".PN.	USPA T	2003/01/0 4 10:45
7	BRS	L7	371	(light adj (intercept\$3 or absorb\$4 or black) with amorphous)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM TDB	2003/01/0 4 11:10
8	BRS	L8	64	7 and (liquid adj crystal or lcd)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM TDB	2003/01/0 4 11:11

	Type	L #	Hits	Search Text	DBs	Time Stamp
9	BRS	L9	44	8 and semiconductor	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2003/01/04 12:13
10	BRS	L10	28	semiconductor adj absorb\$3 adj light	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM- TDB	2003/01/04 12:13